NSN 5961-01-225-8661

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-225-8661

Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

850.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter and 400.0 collector to emitter

voltage/static/base open and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

15.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

Transfer Ratio:

6.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

NSN 5961-01-225-8661 Transistor - Page 2 of 2

Fiig: A110a0

